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a/s

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: YAMAGUCHI, et al.

Serial No.: 09/698,274

Filed: October 30, 2000

For: SEMICONDUCTOR DEVICE, METHOD OF MAKING THE
SAME AND LIQUID CRYSTAL DISPLAY DEVICE

Group: 2826

Examiner: F. Abraham

AMENDMENT

Assistant Commissioner of Patents
Washington, D.C. 20231

August 1, 2002

Sir:

In response to the Office Action mailed May 1, 2002, please amend the
above-identified application as follows:

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IN THE CLAIMS

Please cancel claims 1-3, 11, 16-18 and 34, without prejudice or disclaimer,
and amend the claims remaining in the application as follows:

30. (Amended) A thin-film semiconductor integrated circuit device
comprising a semiconductor thin-film layer provided at the upper part of an insulator,
a plurality of insulated-gate semiconductor elements formed at said semiconductor
thin-film layer, each of said semiconductor elements having a gate electrode
separated from said semiconductor thin-film layer by a gate insulating film at the
surface of said semiconductor thin-film layer, and a seed crystal metal located